



HiPerDynFRED

 $V_{RRM} = 1800 V$ $I_{FAV} = 2x 25 A$

 $t_{rr} = 30 \, \text{ns}$

High Performance Dynamic Fast Recovery Diode Extreme Low Loss and Soft Recovery Parallel legs with series connected dice

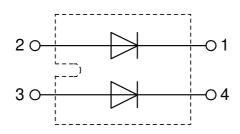
Part number

DPJ50XS1800NA



Backside: isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
 - Power dissipation within the diode
- Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper
- internally DCB isolated

 Advanced power cycling

Disclaimer Notice

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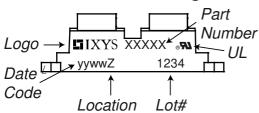
Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocki	ing voltage	$T_{VJ} = 25^{\circ}C$			1800	V
V _{RRM}	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			1800	V
I _R	reverse current, drain current	V _R = 1800 V	$T_{VJ} = 25^{\circ}C$			250	μΑ
		$V_R = 1800 \text{ V}$	$T_{VJ} = 150$ °C			2	mA
V _F	forward voltage drop	I _F = 25 A	$T_{VJ} = 25^{\circ}C$			6.99	V
		$I_F = 50 A$				8.72	V
		I _F = 25 A	T _{VJ} = 150°C			4.33	V
		$I_F = 50 \text{ A}$				5.83	٧
I _{FAV}	average forward current	$T_C = 90^{\circ}C$	T _{VJ} = 150°C			25	Α
		rectangular $d = 0.5$					
V _{F0}	threshold voltage	and a detter and a	$T_{VJ} = 150$ °C			2.92	٧
r _F	slope resistance	oss calculation only				56	mΩ
R_{thJC}	thermal resistance junction to case	e				0.4	K/W
R _{thCH}	thermal resistance case to heatsir	nk			0.1		K/W
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			315	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			250	Α
C¹	junction capacitance	$V_R = 900 \text{V}$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		10		pF
I _{RM}	max. reverse recovery current	<u> </u>	$T_{VJ} = 25 ^{\circ}\text{C}$		9		Α
		$I_F = 30 \text{ A}; V_R = 900 \text{ V}$	$T_{VJ} = 125$ °C		13		Α
t _{rr}	reverse recovery time	$\begin{cases} I_F = 30 \text{ A}; V_R = 900 \text{ V} \\ -di_F /dt = 400 \text{ A}/\mu\text{s} \end{cases}$	$T_{VJ} = 25 ^{\circ}C$		30		ns
)	$T_{VJ} = 125$ °C		140		ns



DPJ50XS1800NA

Package SOT-227B (minibloc)				Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					100	Α
T _{VJ}	virtual junction temperatur	re			-40		150	°C
T _{op}	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		150	°C
Weight						30		g
M _D	mounting torque				1.1		1.5	Nm
\mathbf{M}_{T}	terminal torque				1.1		1.5	Nm
d _{Spp/App}	oroonaga diatanaa an aurt	iona Latrikina diatanaa through air	terminal to terminal	10.5	3.2			mm
d _{Spb/Apb}	creepage distance on surface striking distance thro		terminal to backside	8.6	6.8			mm
V _{ISOL}	isolation voltage	t = 1 second	50/00/11 50/00 1 1/1 4		3000			٧
		t = 1 minute	50/60 Hz, RMS; I _{ISOL} ≤ 1 mA		2500			٧

Product Marking



Part description

D = Diode P = HiPerFRED

J = HiPerDyn +

50 = Current Rating [A]

XS = Parallel legs with series connected dice

1800 = Reverse Voltage [V]

NA = SOT-227B (minibloc)

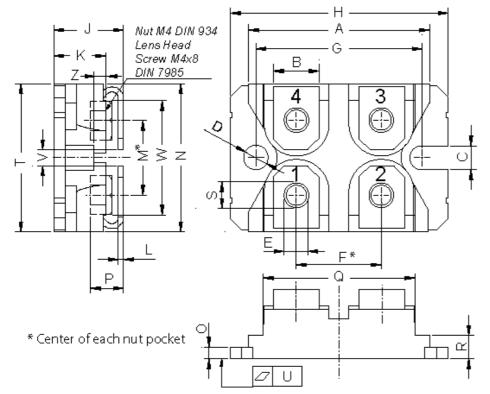
Orderin	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standar	DPJ50XS1800NA	DPJ50XS1800NA	Tube	10	517619

Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 150$ °C
$I \rightarrow V_0$)— <u>R</u> o	Fast Diode		
V _{0 max}	threshold voltage	2.92		V
$R_{0 max}$	slope resistance *	55		mΩ

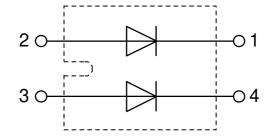




Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches		
Dim.	min	max	min	max	
Α	31.50	31.88	1.240	1.255	
В	7.80	8.20	0.307	0.323	
С	4.09	4.29	0.161	0.169	
D	4.09	4.29	0.161	0.169	
Е	4.09	4.29	0.161	0.169	
F	14.91	15.11	0.587	0.595	
G	30.12	30.30	1.186	1.193	
Н	37.80	38.23	1.488	1.505	
J	11.68	12.22	0.460	0.481	
K	8.92	9.60	0.351	0.378	
L	0.74	0.84	0.029	0.033	
M	12.50	13.10	0.492	0.516	
N	25.15	25.42	0.990	1.001	
0	1.95	2.13	0.077	0.084	
Р	4.95	6.20	0.195	0.244	
Q	26.54	26.90	1.045	1.059	
R	3.94	4.42	0.155	0.167	
S	4.55	4.85	0.179	0.191	
Т	24.59	25.25	0.968	0.994	
U	-0.05	0.10	-0.002	0.004	
V	3.20	5.50	0.126	0.217	
W	19.81	21.08	0.780	0.830	
Ζ	2.50	2.70	0.098	0.106	





Fast Diode

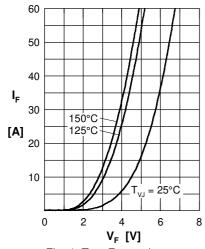


Fig. 1 Typ. Forward current I_F versus V_F

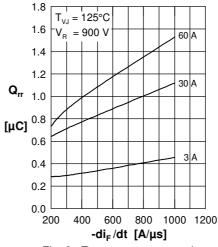


Fig. 2 Typ. reverse recov. charge Q_{rr} versus $-di_F/dt$

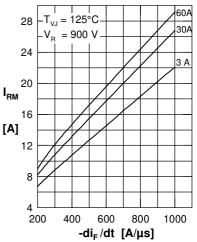


Fig. 3 Typ. reverse recov. current I_{RM} versus $-di_F/dt$

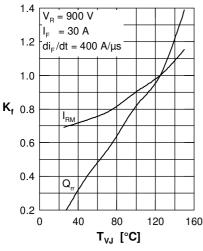


Fig. 4 Typ. dynamic parameters Q_{rr} , I_{RM} versus T_{VJ}

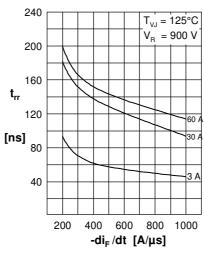


Fig. 5 Typ. reverse recov. time t_{rr} versus $-di_{F}/dt$

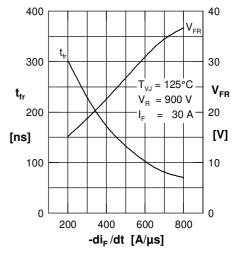


Fig. 6 Typ. forward recov. voltage V_{FR} & time t_{fr} versus di_{F}/dt

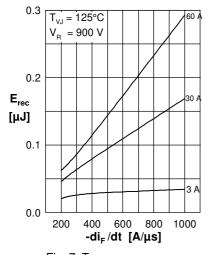


Fig. 7 Typ. recovery energy E_{rec} versus -di_F /dt

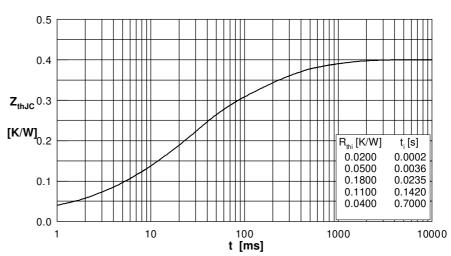


Fig. 8 Transient thermal impedance junction to case

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